1. General description

The 74AXP1G08 is a single 2-input AND gate.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.7 V to 2.75 V. It is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.7 V to 2.75 V
- Low input capacitance; C₁ = 0.5 pF (typical)
- Low output capacitance; C_O = 1.0 pF (typical)
- Low dynamic power consumption; C_{PD} = 2.4 pF at V_{CC} = 1.2 V (typical)
- Low static power consumption; I_{CC} = 0.6 μA (85 °C maximum)
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-12A.01 (1.1 V to 1.3 V)
 - ◆ JESD8-11A.01 (1.4 V to 1.6 V)
 - ◆ JESD8-7A (1.65 V to 1.95 V)
 - ◆ JESD8-5A.01 (2.3 V to 2.7 V)
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001 Class 2 exceeds 2 kV
 - CDM JESD22-C101E exceeds 1000 V
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 2.75 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from –40 °C to +85 °C



3. Ordering information

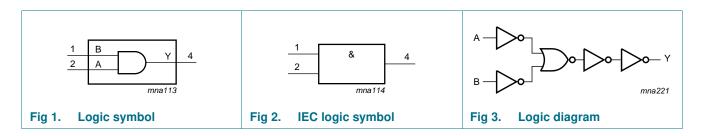
Table 1. Orderin	ng information							
Type number	Package	Package						
	Temperature range	Name	Description	Version				
74AXP1G08GM	–40 °C to +85 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886				
74AXP1G08GN	–40 °C to +85 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74AXP1G08GS	–40 °C to +85 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				
74AXP1G08GX	–40 °C to +85 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74AXP1G08GM	rE
74AXP1G08GN	rE
74AXP1G08GS	rE
74AXP1G08GX	rE

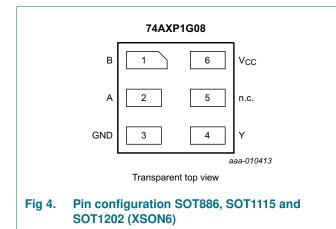
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

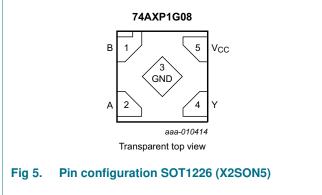
5. Functional diagram



Pinning information 6.

6.1 Pinning





6.2 Pin description

Symbol	Pin		Description
	X2SON5	XSON6	
В	1	1	data input
A	2	2	data input
GND	3	3	ground (0 V)
Y	4	4	data output
n.c.	-	5	not connected
V _{CC}	5	6	supply voltage

7. Functional description

Table 4. Function table^[1]

Input		Output
Α	В	Y
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

[1] H = HIGH voltage level; L = LOW voltage level.

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+3.3	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+3.3	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage		<u>[1]</u> –0.5	+3.3	V
lo	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +85 \ ^{\circ}C$	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.7	2.75	V
VI	input voltage		0	2.75	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	2.75	V
T _{amb}	ambient temperature		-40	+85	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 0.7 \text{ V}$ to 2.75 V	0	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions, unless otherwise specified; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions			$T_{amb} = -40$	°C to +85 °C	;	Uni
				Min	Typ 25 °C	Max 25 °C	Max 85 °C	
∕ _{IH}	HIGH-level input	V _{CC} = 0.75 V to 0.85 V		$0.75V_{CC}$	-	-	-	V
	voltage	V _{CC} = 1.1 V to 1.95 V		$0.65V_{CC}$	-	-	-	V
		$V_{CC} = 2.3 \text{ V}$ to 2.7 V		1.6	-	-	-	V
VIL	LOW-level input	$V_{CC} = 0.75 \text{ V} \text{ to } 0.85 \text{ V}$		-	-	$0.25V_{CC}$	$0.25V_{CC}$	V
	voltage	V _{CC} = 1.1 V to 1.95 V		-	-	$0.35V_{CC}$	$0.35V_{CC}$	V
		$V_{CC} = 2.3 \text{ V}$ to 2.7 V		-	-	0.7	0.7	V
√ _{ОН}	HIGH-level	$I_{O} = -20 \ \mu A; V_{CC} = 0.7 \ V$		-	0.69	-	-	V
output voltage	$I_{O} = -100 \ \mu A; V_{CC} = 0.75 \ V$		0.65	-	-	-	V	
	$I_O = -2 \text{ mA}; V_{CC} = 1.1 \text{ V}$		0.825	-	-	-	V	
		$I_{O} = -3 \text{ mA}; V_{CC} = 1.4 \text{ V}$		1.05	-	-	-	V
		$I_{O} = -4.5 \text{ mA}; V_{CC} = 1.65 \text{ V}$		1.2	-	-	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$		1.7	-	-	-	V
/ _{OL}	LOW-level	$I_{O} = 20 \ \mu A; \ V_{CC} = 0.7 \ V$		-	0.01	-	-	V
	output voltage	$I_O = 100 \ \mu A; \ V_{CC} = 0.75 \ V$		-	-	0.1	0.1	V
		$I_{O} = 2 \text{ mA}; V_{CC} = 1.1 \text{ V}$		-	-	0.275	0.275	V
		$I_{O} = 3 \text{ mA}; V_{CC} = 1.4 \text{ V}$		-	-	0.35	0.35	V
		$I_{O} = 4.5 \text{ mA}; V_{CC} = 1.65 \text{ V}$		-	-	0.45	0.45	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$		-	-	0.7	0.7	V
I	input leakage current	$V_{I} = 0 V \text{ to } 2.75 V;$ $V_{CC} = 0 V \text{ to } 2.75 V$	[1]	-	0.001	±0.1	±0.5	μA
OFF	power-off leakage current	$V_1 \text{ or } V_O = 0 \text{ V to } 2.75 \text{ V};$ $V_{CC} = 0 \text{ V}$	[1]	-	0.01	±0.1	±0.5	μA
N _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V or } 2.75 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.1 \text{ V}$	<u>[1]</u>	-	0.02	±0.1	±0.5	μA
СС	supply current	$V_I = 0 V \text{ or } V_{CC}; I_O = 0 A$	<u>[1]</u>	-	0.01	0.3	0.6	μA
∆I _{CC}	additional supply current			-	2	100	150	μA

[1] All typical values are measured at V_{CC} = 1.2 V.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 12.

Symbol	Parameter	Conditions		T _{amb} = 25 °C			T _{amb} = -40 °C to +85 °C		Unit
				Min	Typ <mark>[1]</mark>	Max	Min	Max	
t _{pd}	propagation	A, B to Y; see Figure 6	[2][3]						
	delay	$V_{CC} = 0.75 \text{ V} \text{ to } 0.85 \text{ V}$		3	11	37	2	122	ns
		V _{CC} = 1.1 V to 1.3 V		2.0	4.3	6.9	1.8	7.3	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		1.6	3.2	4.7	1.5	5.0	ns
		V _{CC} = 1.65 V to 1.95 V		1.3	2.6	3.8	1.2	4.1	ns
		V_{CC} = 2.3 V to 2.7 V		1.1	2.0	2.8	0.9	3.0	ns
tt	transition time	$V_{CC} = 2.7 \text{ V}; \text{ see } \frac{\text{Figure 6}}{100000000000000000000000000000000000$	[4]	-	-	-	1.0	-	ns
Cı	input capacitance			-	0.5	-	-	-	pF
C _O	output capacitance	$V_O = 0 V; V_{CC} = 0 V$		-	1.0	-	-	-	pF
C _{PD}		$f_i = 1 \text{ MHz}; V_I = 0 \text{ V to } V_{CC}$	[5]						
	capacitance	$V_{CC} = 0.75 \text{ V} \text{ to } 0.85 \text{ V}$		-	2.3	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V		-	2.4	-	-	-	pF
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		-	2.4	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V		-	2.5	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V		-	2.8	-	-	-	pF

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[3] For additional propagation delay values at different load capacitances see Figure 7 to Figure 11.

[4] t_t is the same as t_{THL} and t_{TLH} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + C_L \times V_{CC}^2 \times f_o$ where:

 $f_i = input frequency in MHz;$

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching.

Low-power 2-input AND gate

12. Waveforms

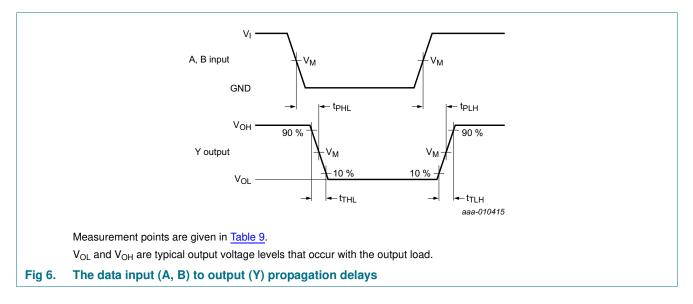
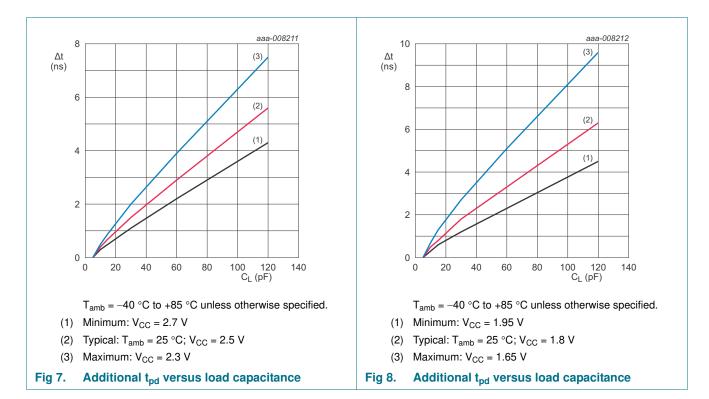


Table 9. Measurement points

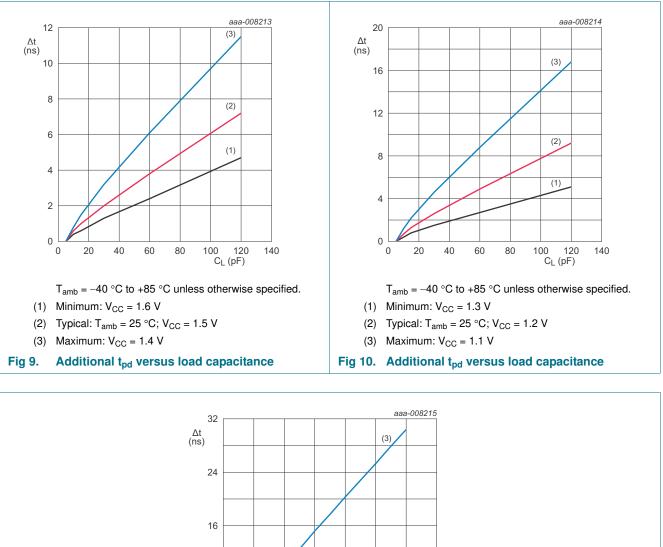
Supply voltage	Input			Output
V _{cc}	V _M	VI	t _r = t _f	V _M
0.75 V to 2.7 V	0.5V _{CC}	V _{CC}	≤ 3.0 ns	0.5V _{CC}



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 $T_{amb} = -40 \text{ °C to } +85 \text{ °C unless otherwise specified.}$

- (2) Typical: $T_{amb} = 25 \text{ °C}$; $V_{CC} = 0.8 \text{ V}$
- (3) Maximum: $V_{CC} = 0.75 V$
- Fig 11. Additional t_{pd} versus load capacitance

Low-power 2-input AND gate

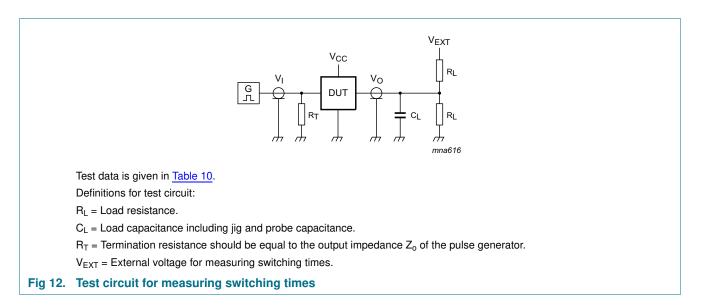


Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	RL	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.75 V to 2.7 V	5 pF	10 kΩ	0 V	0 V	$2 \times V_{CC}$

13. Package outline

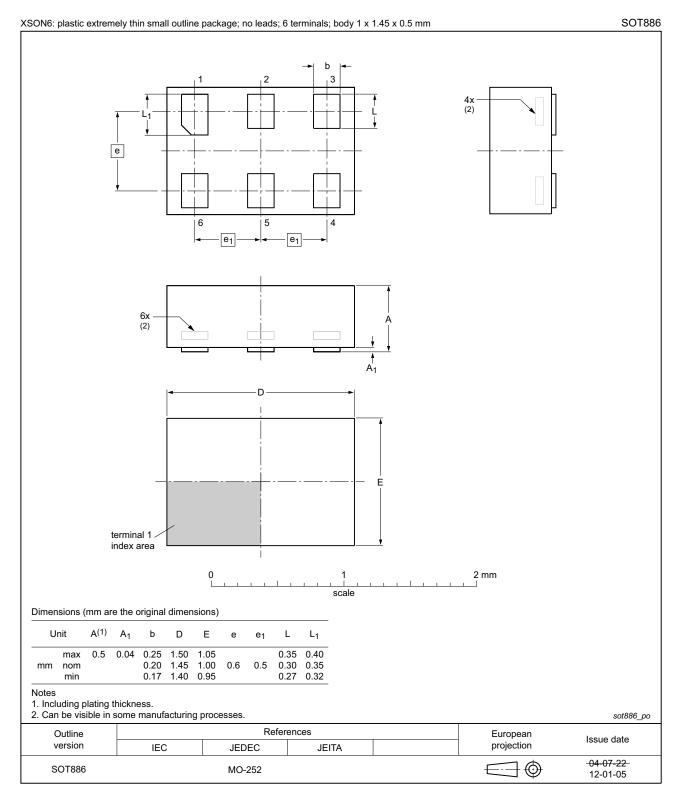
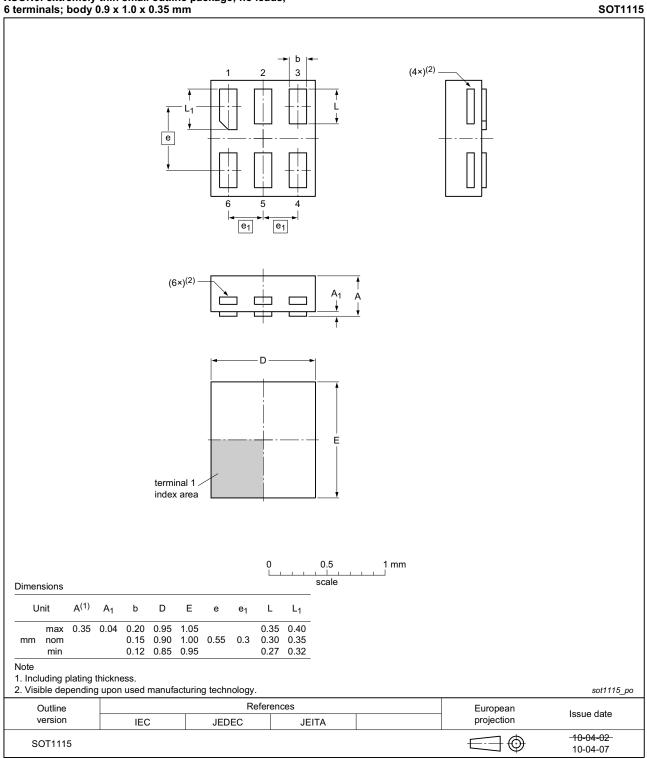


Fig 13. Package outline SOT886 (XSON6)

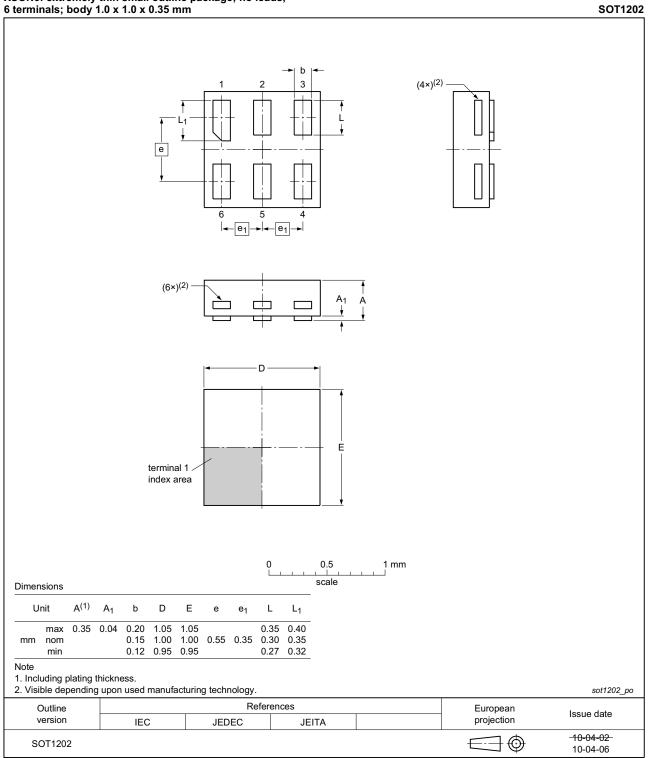
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XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 14. Package outline SOT1115 (XSON6)

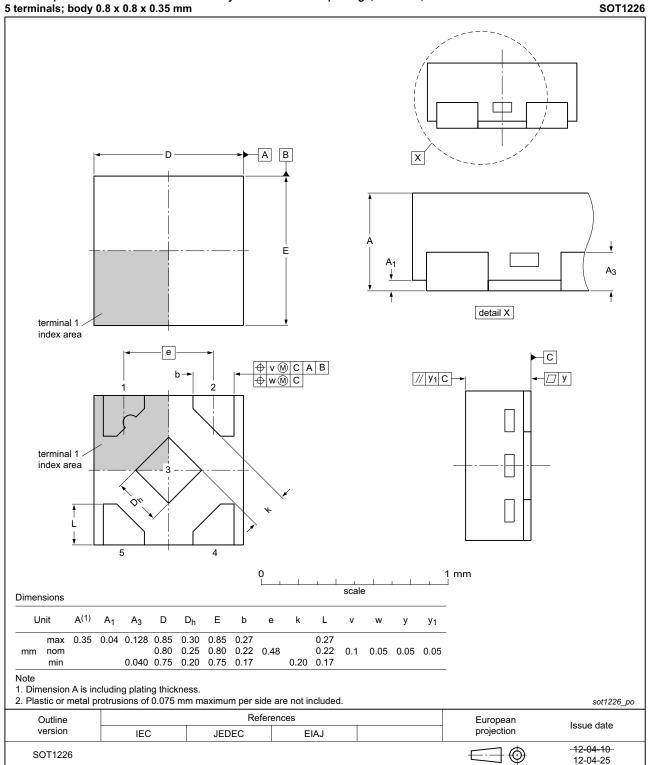
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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1202 (XSON6)

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X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.35 mm

Fig 16. Package outline SOT1226 (X2SON5)

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14. Abbreviations

Table 11.	Abbreviations
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model

15. Revision history

Table 12. Revisio	n history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AXP1G08 v.2	20140121	Product data sheet	-	74AXP1G08 v.1
Modifications:	• Table 1 and	Table 2: corrected type numbers	S	
74AXP1G08 v.1	20140115	Product data sheet	-	-
-				

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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